

SEMICONDUCTOR IM

May 1995 Revis<mark>ed February 2001</mark> 4LCX157 Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs

74LCX157 Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs

General Description

The LCX157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The LCX157 can also be used as a function generator. The 74LCX157 is fabricated with advanced CMOS technol-

ogy to achieve high speed operation while maintaining CMOS low power dissipation.

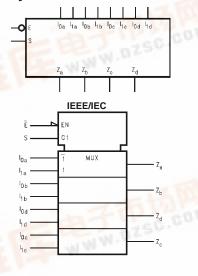
Features

- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.8 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance inputs and outputs
- ± 24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description			
74LCX157M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow			
74LCX157SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
74LCX157MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
Devices also available	Devices also available in Tane and Reel. Specify by appending the suffix letter "X" to the ordering code				

Logic Symbols



Connection Diagram

s —		16 - V _{CC}
-0a -	2	15 — Ē
1a —	3	14 – I _{0c}
Z _a —	4	13 — I _{1c}
I _{0b} —	5	1 2 🗕 Z _e
I _{1b} —	6	1 1 🖵 I _{0d}
z _b —	7	10 – I _{1d}
GND —	8	9 — Z _d
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Pin Descriptions

Pin Names	Description
I _{0a} –I _{0d}	Source 0 Data Inputs
I _{1a} –I _{1d}	Source 1 Data Inputs
Ē	Enable Input
S	Select Input
Z _a –Z _d	Outputs



Functional Description

The LCX157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input (\overline{E}) is active-LOW. When \overline{E} is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The LCX157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

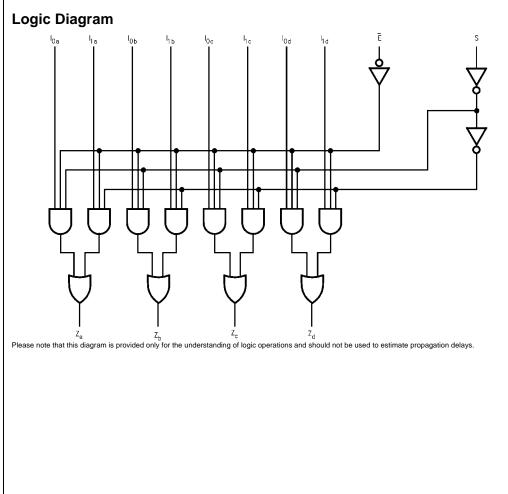
 $Z_a = \overline{E} \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S})$ $Z_{b} = \overline{E} \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S})$ $Z_{c} = \overline{\mathsf{E}} \bullet (\mathsf{I}_{1c} \bullet \mathsf{S} + \mathsf{I}_{0c} \bullet \overline{\mathsf{S}})$ $Z_{d} = \overline{E} \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S})$

A common use of the LCX157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The LCX157 can generate any four of the sixteen different functions of two variables with one variable common. This is useful for implementing gating functions.

Truth Table

	Inputs			Outputs
Ē	S	I ₀	I ₁	Z
Н	Х	Х	Х	L
L	н	х	L	L
L	н	Х	н	н
L	L	L	х	L
L	L	н	х	н
H = HIGH Vol	tage Level			

L = LOW Voltage Level X = Immaterial



Absolute Maximum Ratings(Note 1)

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Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
VI	DC Input Voltage	-0.5 to +7.0		V	
Vo	DC Output Voltage	-0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 2)	V	
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA	
		+50	$V_{O} > V_{CC}$	mA	
I _O	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
I _{GND}	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 3)

Symbol	/mbol Parameter			Max	Units
V _{CC}	Supply Voltage Open	ating	2.0	3.6	V
	Data Rete	ntion	1.5	3.6	v
VI	Input Voltage		0	5.5	V
V _O	Output Voltage HIGH or LOW S	State	0	V _{CC}	V
I _{OH} /I _{OL}	Output Current $V_{CC} = 3.0V -$	3.6V		<u>+2</u> 4	
	Output Current $V_{CC} = 3.0V - V_{CC} = 2.7V - V_{CC} = 2.7V$	3.0V		±12	mA
	V _{CC} = 2.3V -	2.7V		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_{O} Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C$	to +85°C	Units
Gymbol	. arameter	Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		v
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	v
			2.7 – 3.6		0.8	v
V _{ОН}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		•
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		•
		I _{OH} = -24 mA	3.0	2.2		•
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OH} = 8 mA	2.3		0.6	
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	•
lı	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ
I _{OFF}	Power-Off Leakage Current	$V_{I} \text{ or } V_{O} = 5.5 V$	0		10	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		10	μA
		$3.6V \leq V_l \leq 5.5V$	2.3 - 3.6		±10	μΛ
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μΑ

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AC Electrical Characteristics

Symbol		$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500\Omega$						
	Demonster	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
	Parameter							
		Min	Max	Min	Max	Min	Max	1
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	
t _{PLH}	$S \rightarrow Z_n$	1.5	7.0	1.5	8.0	1.5	8.4	ns
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	1
t _{PLH}	$\overline{E} \rightarrow Z_n$	1.5	7.0	1.5	8.0	1.5	8.4	ns
t _{PHL}	Propagation Delay	1.5	5.8	1.5	6.3	1.5	7.0	
t _{PLH}	$I_n \rightarrow Z_n$	1.5	5.8	1.5	6.3	1.5	7.0	ns
t _{OSHL}	Output to Output Skew		1.0					ns
t _{OSLH}	(Note 4)		1.0					115

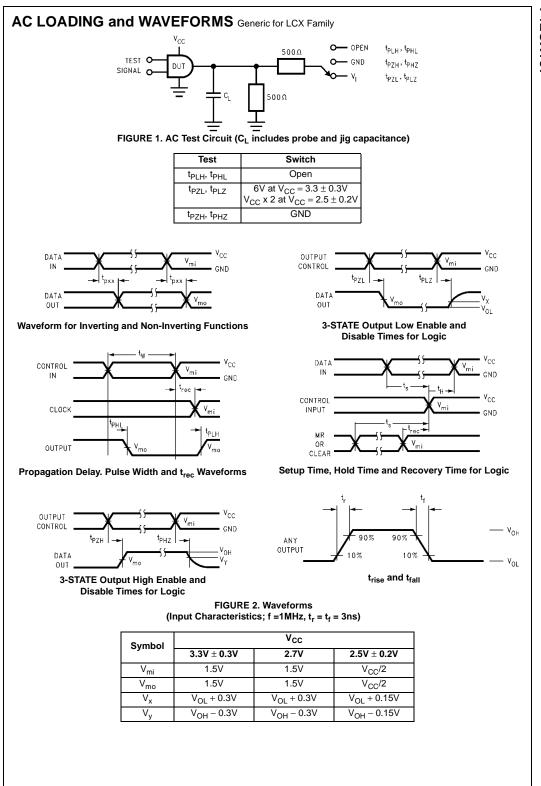
Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

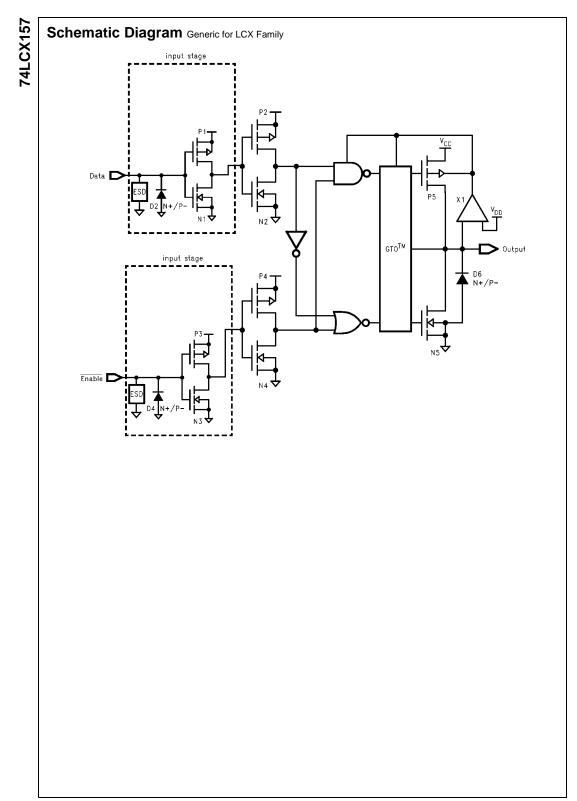
Symbol	Parameter	Conditions	V _{cc}	$T_A = 25^{\circ}C$	Units
Gymbol		Conditions	(V)	Typical	onito
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_{L} = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	0.8	V
		CL= 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	-0.8	V
		CL= 30 pF, V_{IH} = 2.5V, V_{IL} = 0V	2.5	-0.6	v

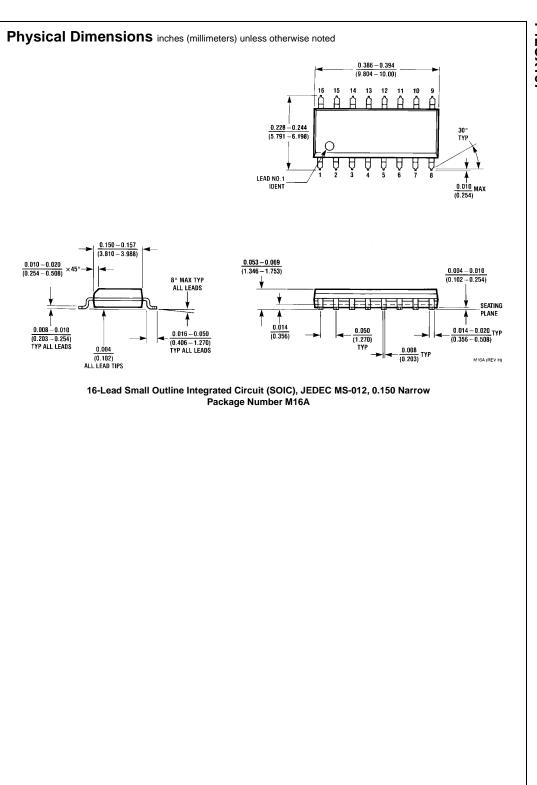
Capacitance

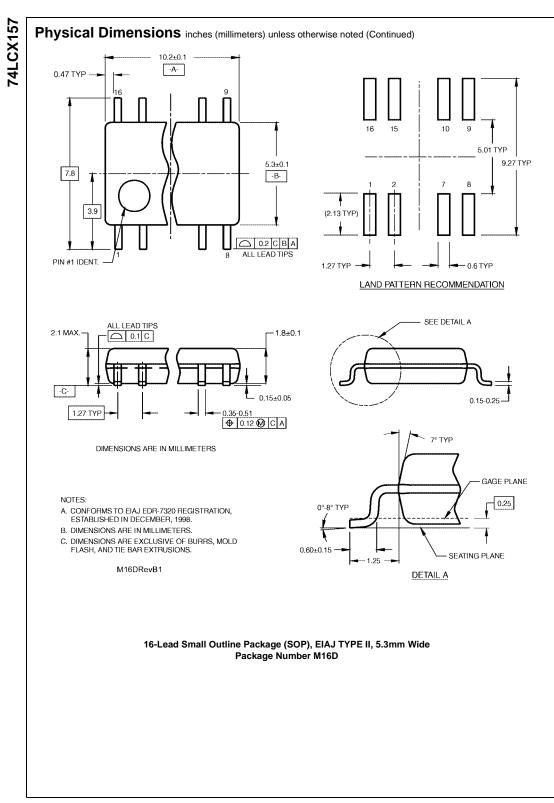
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	25	pF



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